NSN 5962-01-344-9319

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View Online at https://aerobasegroup.com/nsn/5962-01-344-9319

Overall Length:
1.285 inches
Overall Height:
0.325 inches
Body Length:
1.285 inches
Body Width:
0.600 inches
Body Height:
0.175 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and hermetically sealed and burn in and w/enable and programmable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Hi-performance mos
Input Circuit Pattern:
22 input
Criticality Code Justification:
Feat
Current Rating Per Characteristic:
140.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.0 volts power source
Capitance Rating Per Characteristic:
Err-060 and err-060
Time Rating Per Chacteristic:
350.00 nanoseconds delay
Memory Device Type:
Eeprom
Special Features:
Nuclear hardness critical item
Unpackaged Unit Weight:

6.5 grams

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	Ī	erminal	Type	And	Quantit	y:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0